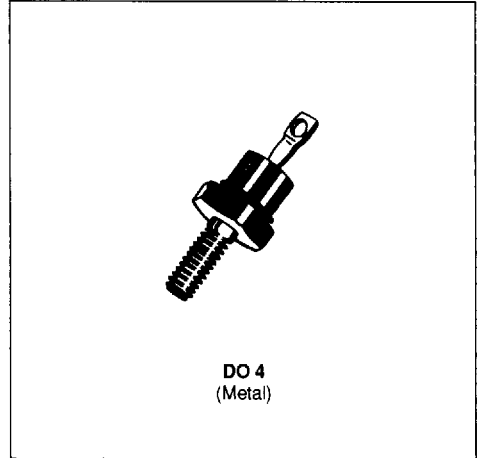


## HIGH EFFICIENCY FAST RECOVERY RECTIFIER DIODES

- VERY LOW CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD AND REVERSE RECOVERY TIMES
- HIGH SURGE CURRENT AND AVALANCHE CAPABILITY
- THE SPECIFICATIONS AND CURVES ENABLE THE DETERMINATION OF  $t_{tr}$  AND  $I_{RM}$  AT 100°C UNDER USERS CONDITIONS



### DESCRIPTION

Low voltage drop rectifiers suited for switchmode power supply.

### ABSOLUTE RATINGS (limiting values)

| Symbol      | Parameter                            |                                       | Value               | Unit |
|-------------|--------------------------------------|---------------------------------------|---------------------|------|
| $I_{FRM}$   | Repetitive Peak Forward Current      | $t_p \leq 20\mu s$                    | 200                 | A    |
| $I_F (RMS)$ | RMS Forward Current                  |                                       | 35                  | A    |
| $I_F (AV)$  | Average Forward Current              | $T_C = 120^\circ C$<br>$\delta = 0.5$ | 15                  | A    |
| $I_{FSM}$   | Surge non Repetitive Forward Current | $t_p = 10ms$<br>Sinusoidal            | 200                 | A    |
| $P_{tot}$   | Power Dissipation                    |                                       | $T_C = 100^\circ C$ | W    |
| $T_J$       | Junction Temperature                 |                                       | - 40 to 150         | °C   |

| Symbol    | Parameter                           | BYW 81- |     |     |     | Unit |
|-----------|-------------------------------------|---------|-----|-----|-----|------|
|           |                                     | 50      | 100 | 150 | 200 |      |
| $V_{RRM}$ | Repetitive Peak Reverse Voltage     | 50      | 100 | 150 | 200 | V    |
| $V_{RSM}$ | Non Repetitive Peak Reverse Voltage | 55      | 110 | 165 | 220 | V    |

### THERMAL RESISTANCE

| Symbol        | Parameter     | Value | Unit |
|---------------|---------------|-------|------|
| $R_{th(j-c)}$ | Junction-case | 2.3   | °C/W |

**ELECTRICAL CHARACTERISTICS**

**STATIC CHARACTERISTICS**

| Symbol         | Test Conditions        |                                   | Min. | Typ. | Max. | Unit |
|----------------|------------------------|-----------------------------------|------|------|------|------|
| I <sub>R</sub> | T <sub>J</sub> = 25°C  | V <sub>R</sub> = V <sub>RRM</sub> |      |      | 15   | μA   |
|                | T <sub>J</sub> = 100°C |                                   |      |      | 1.5  | mA   |
| V <sub>F</sub> | T <sub>J</sub> = 25°C  | I <sub>F</sub> = 38A              |      |      | 1.25 | V    |
|                | T <sub>J</sub> = 100°C | I <sub>F</sub> = 12A              |      |      | 0.85 |      |

**RECOVERY CHARACTERISTICS**

| Symbol          | Test Conditions   |                                      |                                | Min. | Typ. | Max. | Unit |
|-----------------|---|--------------------------------------|--------------------------------|------|------|------|------|
| t <sub>rr</sub> | T <sub>J</sub> = 25°C<br>V <sub>R</sub> = 30V             | I <sub>F</sub> = 1A<br>see figure 12 | di <sub>F</sub> /dt = - 50A/μs |      |      | 35   | ns   |
| Q <sub>rr</sub> | T <sub>J</sub> = 25°C<br>V <sub>R</sub> ≤ 30V             | I <sub>F</sub> = 2A                  | di <sub>F</sub> /dt = - 20A/μs |      |      | 15   | nC   |
| t <sub>fr</sub> | T <sub>J</sub> = 25°C<br>Measured at 1.1 x V <sub>F</sub> | I <sub>F</sub> = 1A                  | t <sub>r</sub> = 5ns           |      | 15   |      | ns   |
| V <sub>FP</sub> | T <sub>J</sub> = 25°C                                     | I <sub>F</sub> = 1A                  | t <sub>r</sub> = 5ns           |      | 2    |      | V    |

To evaluate the conduction losses use the following equations :

$$V_F = 0.66 + 0.0077 I_F$$

$$P = 0.66 \times I_{F(AV)} + 0.0077 I_{F(RMS)}^2$$

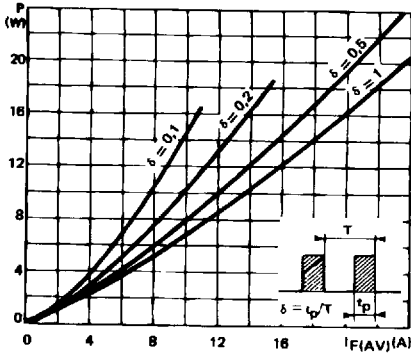


FIGURE 1 : Power losses versus average current

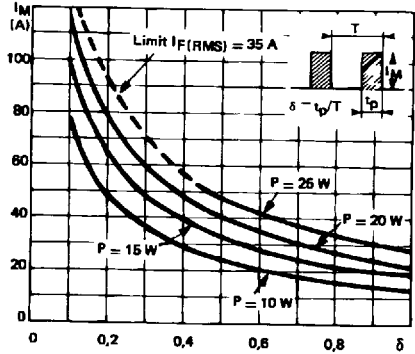


FIGURE 2 : Peak current versus form factor

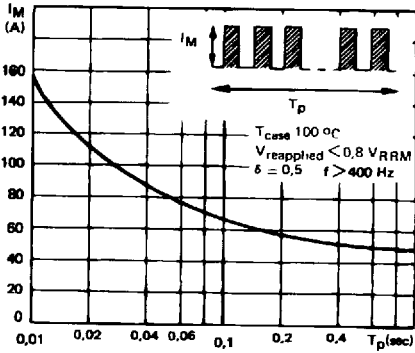


FIGURE 3 : Non repetitive peak surge current versus duration

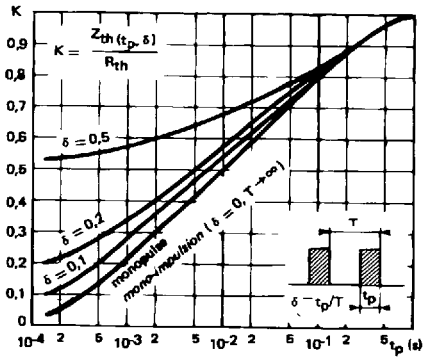


FIGURE 4 : Thermal impedance versus pulse width

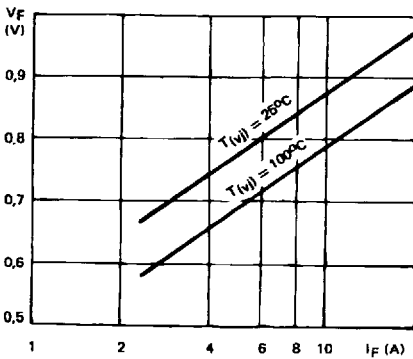


FIGURE 5 : Voltage drop versus forward current

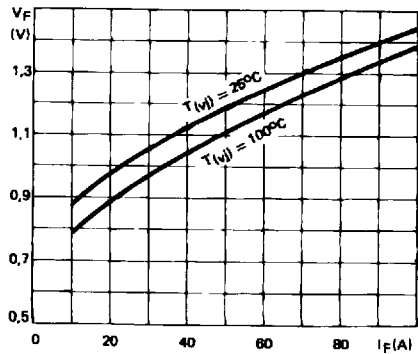


FIGURE 6 : Voltage drop versus forward current

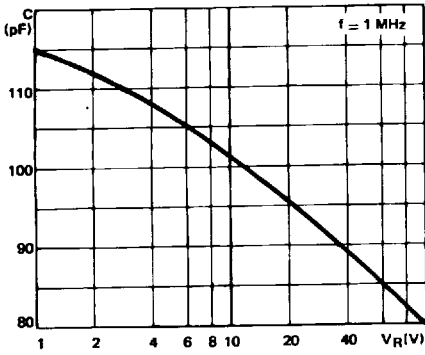


FIGURE 7 : Capacitance versus reverse voltage applied

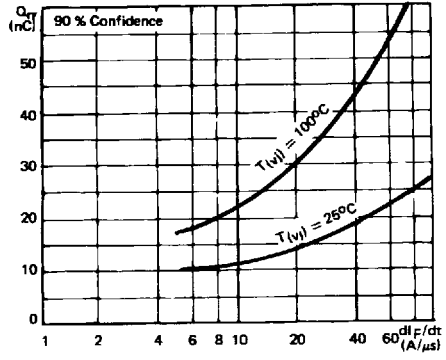


FIGURE 8 : Recovery charge versus  $di_F/dt$

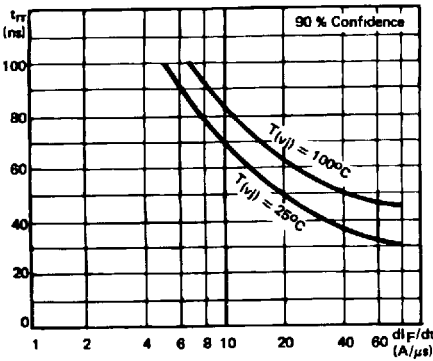


FIGURE 9 : Recovery time versus  $di_F/dt$

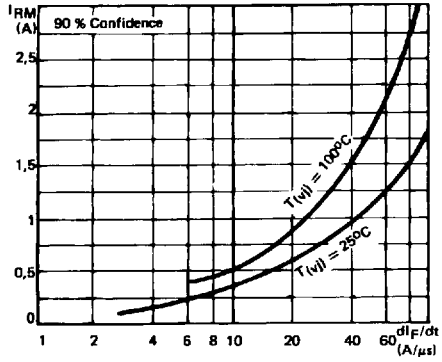


FIGURE 10 : Peak reverse current versus  $di_F/dt$

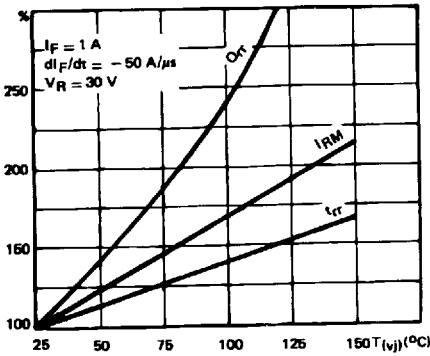


FIGURE 11 : Dynamic parameters versus junction temperature

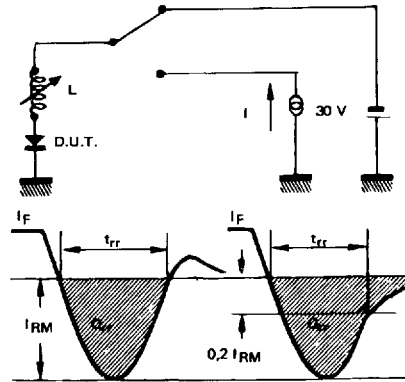


FIGURE 12 : Measurement of  $t_{rr}$  (fig. 9) and  $I_{RM}$